

# **Schottky Barrier Rectifier** DST1040S-A, 10A, 45V, TO-277B, Single

# DST1045S-A



#### Pin out



#### Description

Littelfuse DST series Ultra Low VF Schottky Barrier Rectifier is designed to meet the general requirements of automotive applications by providing high temperature, low leakage and low VF products.

It is suitable for high frequency switching mode power supply applications, as free-wheeling and polarity protection diodes.

#### Features

- Ultra low forward voltage drop
  - Single die in TO-277B Package
- High frequency operation
- High junction temperature capability
- High reliability application and AEC-Q101 qualified
- Trench MOS Barrier

#### Applications

- Switching mode power supply
- Free-Wheeling diodes

Schottky technology

Polarity Protection Diodes

HF RoHS 63

DC/DC converters

#### **Maximum Ratings**

Parameters	Symbol	Test Conditions	Мах	Unit
Peak Inverse Voltage	V <sub>RWM</sub>	-	45	V
Average Forward Current *	I <sub>F(AV)</sub>	50% duty cycle @T <sub>L</sub> = 125 °C rectangular wave form	10	A
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

\* Mounted on 30 mm x 30 mm pad areas aluminum PCB

#### **Electrical Characteristics**

Parameters	Symbol	Test Conditions	Тур	Мах	Unit
Forward Voltage Drop *	V	@5A, Pulse, T <sub>J</sub> = 25 °C	0.43	0.51	- V
	V <sub>F1</sub>	@10A, Pulse, T <sub>J</sub> = 25 °C	0.49	0.57	
	N/	@5A, Pulse, T <sub>J</sub> = 125 °C	0.32	0.43	
	V <sub>F2</sub>	@10A, Pulse, T <sub>J</sub> = 125 °C	0.41	0.50	
Reverse Current *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.003	0.019	mA
neverse Current	I <sub>R2</sub>	$@V_{R} = rated V_{R} T_{J} = 125 °C$	5	15	IIIA
Junction Capacitance	C <sub>T</sub>	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C, f <sub>SIG</sub> = 1MHz	656	-	pF

\* Pulse Width < 300µs, Duty Cycle <2%

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### **Thermal-Mechanical Specifications**

Parameters	Symbol	Test Conditions	Мах	Unit
Junction Temperature	Tj	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Thermal Resistance Junction to Ambient	R <sub>eja</sub>	DC operation	75	°C/W
Typical Thermal Resistance Junction to Lead	R <sub>eJL</sub> *	DC operation	3.5	°C/W
Approximate Weight	vvt	-	0.08	g
Case Style	ТО-277В			

(1) Free air, mounted on recommended copper pad area; thermal resistance  $R_{\Theta_{iA}}$ - junction to ambient (2) Mounted on 30 mm x 30 mm pad areas aluminum PCB; thermal resistance  $R_{\Theta_{iI}}$ - junction to lead \*Lead temperature monitored at the cathode pin

### Figure 1: Forward Current Derating Curve



# Figure 3: Typical Instantaneous Forward Voltage Characteristics



## Figure 2: Forward Power Loss Characteristics



## Figure 4: Typical Reverse Characteristics





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#### Figure 5: Typical Junction Capacitance



### **Dimensions-TO-277B**



Symbol	Millimeters			
	Min	Тур	Мах	
А	6.30	6.50	6.70	
В	3.88	3.98	4.08	
С	0.95	1.10	1.25	
D	0.20	0.25	0.30	
E	5.28	5.38	5.48	
F	3.40	3.55	3.70	
G	2.90	3.05	3.20	
Н	1.74	1.84	1.94	
I	1.10	1.25	1.40	
J	-	0.85	-	
К	1.70	1.80	1.90	
L	0.85	0.90	0.95	
М	-	0.56	-	



#### **Mounting Pad Layout**



#### Part Numbering and Marking System



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